

SIXTEENTH ANNUAL

BiTS™

Burn-in & Test Strategies Workshop

March 15 - 18, 2015

Hilton Phoenix / Mesa Hotel
Mesa, Arizona



Archive – Session 1

Session 1

Marc Mössinger
Session Chair

BiTS Workshop 2015 Schedule

Frontiers Day

Monday March 16 10:30 am

Putting MEMS to the Test

"Taking MEMS Test and Calibration to the Next Level' - An Integrated Platform Approach Driving Further MEMS Growth"

John Rychcik - Xcerra Corporation

"The Target for Consumer MEMS Testing Should Be Under 1 Cent Level"

Vesa Henttonen - Afore Oy

"MEMS IC Manufacturing Test Cost Effective Strategies"

Wendy Chen & Andrei Berar - KYEC

"BURst Pressure (BURP) Stress Test for MEMS Pressure Sensors"

Peter Jones & Ray Sessego - Freescale Semiconductor

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BURst Pressure (BURP) Stress Test for MEMS Pressure Sensors

Peter Jones
Raimondo Sessego
Freescale Semiconductor



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Overview

- **BURst Pressure (BURP) Stress Test**
- Custom wafer level pressure test system design and fabrication
- Used to verify differential pressure sensor meets minimum pressure strength specification.
- Built internally by Freescale Semiconductor.
- 200 mm wafer
- Pressures up to 2000 kPaG (290 psig, 20 bar(g)) for single device parallelism
- x2 Parallelism for production test pressures 500 kPaG (73 psig, 5 bar(g))



Sensors Solutions Division

	Pressure	Automotive, industrial, medical and consumer absolute and differential sensors <i>Flow, comfort management, HVAC, medical, engine control</i>
	Accelerometer	Consumer and industrial low-g sensors and tilt sensors Automotive medium- and high-g crash sensors <i>Vehicle stability, airbag, vibration monitor, tilt alignment</i>
	Magnetometer	Consumer and industrial magnetic field sensor and 3D compass <i>Orientation alignment, proximity detection, magnetic switch</i>
	Gyroscope	Consumer and industrial angular rate sensors and 6/9-DOF IMU Automotive roll sensor and IMU <i>Stabilization, motion and gesture HMI, inertial navigation, gaming</i>
	Sensing systems	Consumer and industrial MCU and sensor integrated platforms Automotive tire pressure monitoring system <i>Smart sensors, pedometer, anti-tamper, fault prognostication</i>

Automotive Pressure Sensors

Manifold Absolute Pressure (MAP)

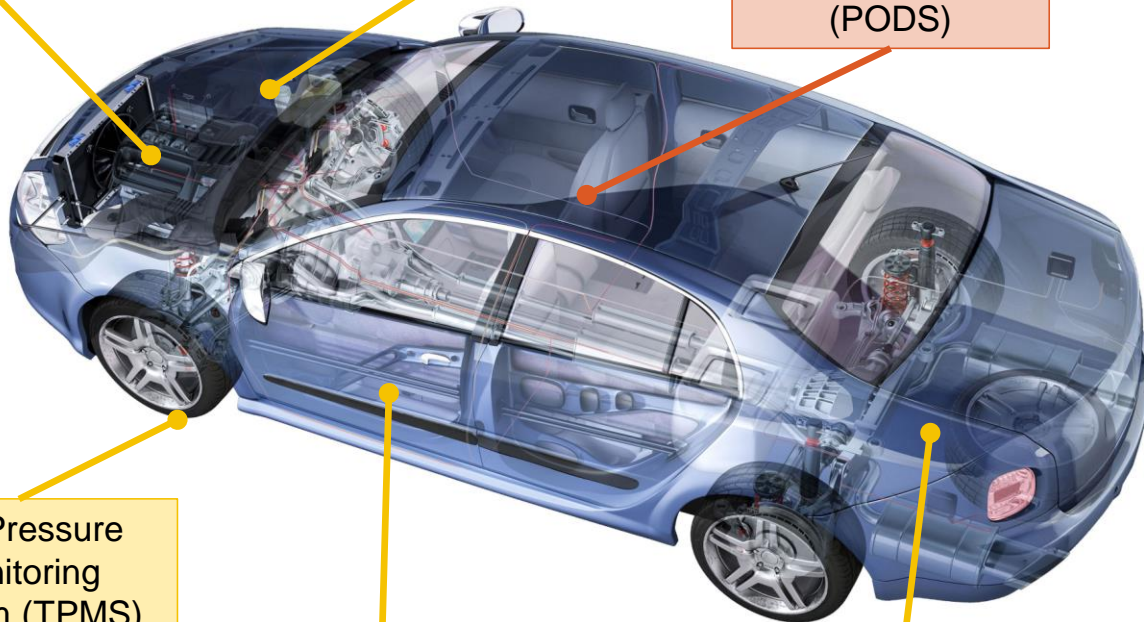
Barometric Air Pressure (BAP)

Passive Occupant Detection System (PODS)

Tire Pressure Monitoring System (TPMS)

Side Airbag Impact Sensor

Fuel Vapor Pressure Sensor



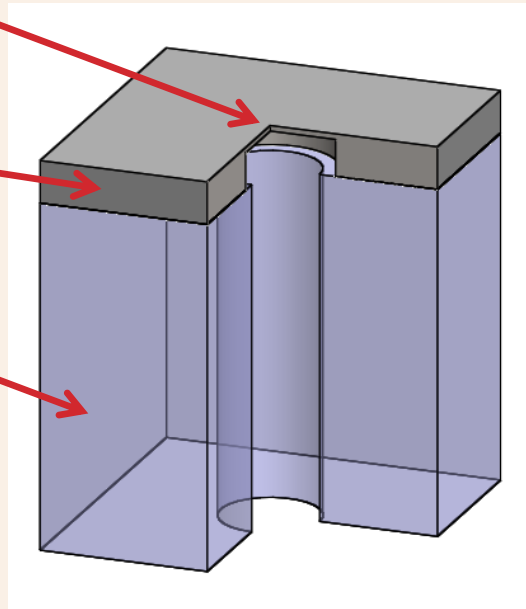
PODS Device

- Device is an approximate cube with a ~3mm length each side.
- Backside, Differential Pressure Sensor

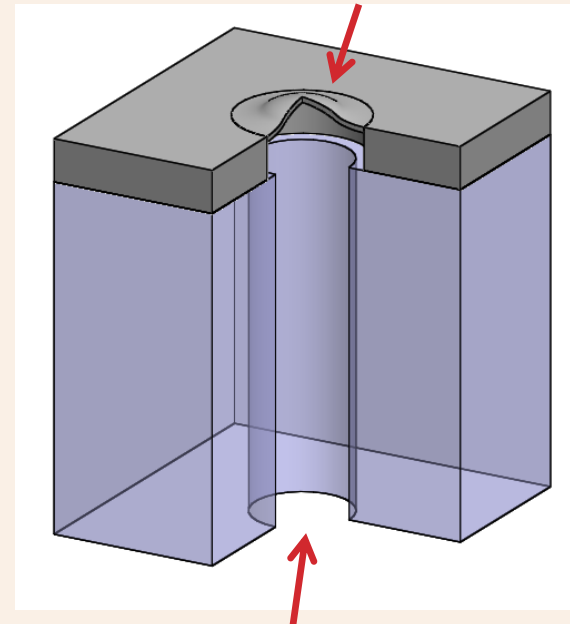
Diaphragm (Sense Element)

Silicon
Device
Layer

Glass
Substrate



P2 – Reference Pressure
(typically Atmospheric)



P1 – Sense Pressure

Problem Statement

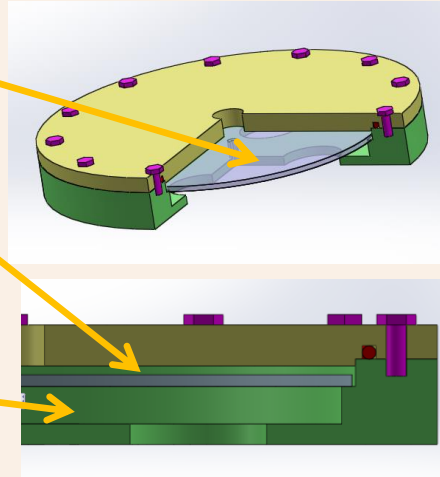
- Customer found pressure sensors would fail (diaphragm would burst) at pressures lower than the design specification 450 kPaG (65 psig, 4.5 bar(g)).
- Device is sold in die form, so no opportunity to test a fully packaged device (something that would make testing the design pressure easy).
- Prefer to test while devices are still in wafer form, before singulation.
- Apply 500 kPaG (73 psig, 5 bar(g)) to the device's backside.
- Wafer 200 mm diameter, 3.481 mm thick. Silicon wafer bonded to thick glass substrate.
- 2611 usable die on wafer.

Proposed Solutions

Wafer loaded device
side down

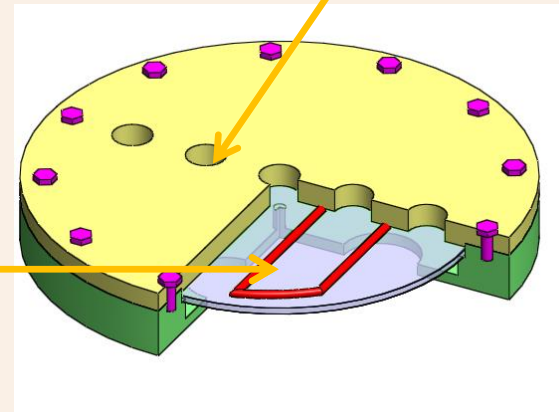
Top of pressure
vessel pressurized
450-500 kPaG

Bottom of pressure
vessel vented to
atmosphere



There will be **3,500 lb** (15.7 kN) of force when the vessel is pressurized to 500 kPaG (73 psig, 5 bar (g)).

Multiple pressure
ports



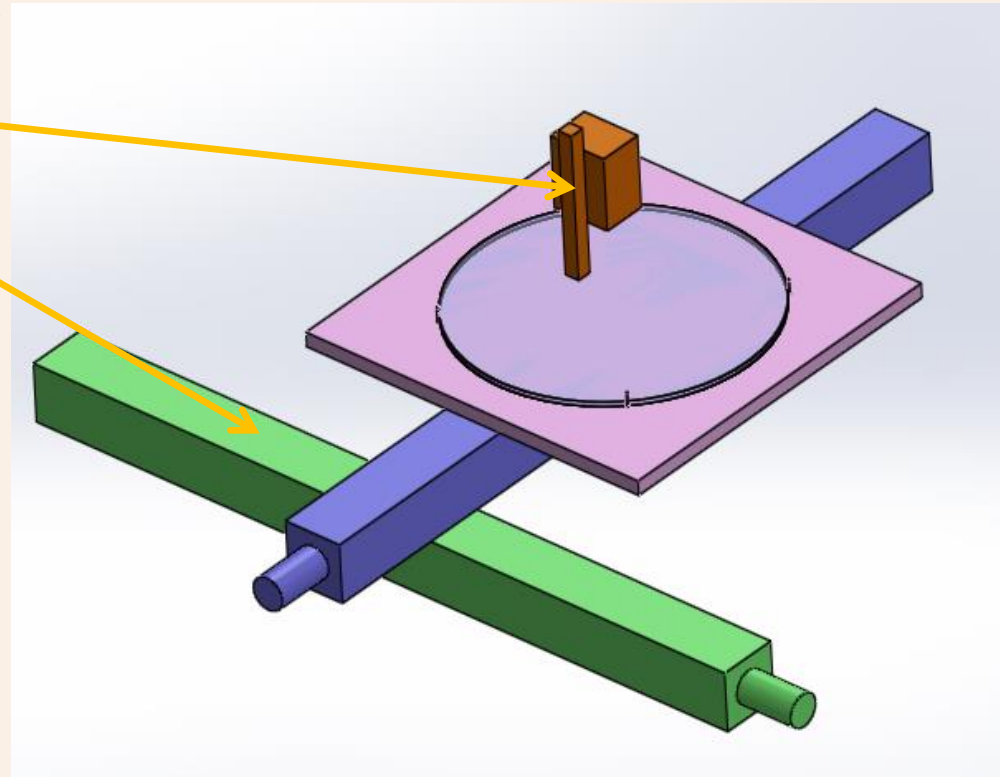
O-rings touching
back side of wafer
required to section
off smaller pressure
areas.

Final Concept Test Small Portion of Wafer – Pressure Nozzle w/ XY Stage

Pressure Nozzle w/
Force Controlled Z-
axis stage

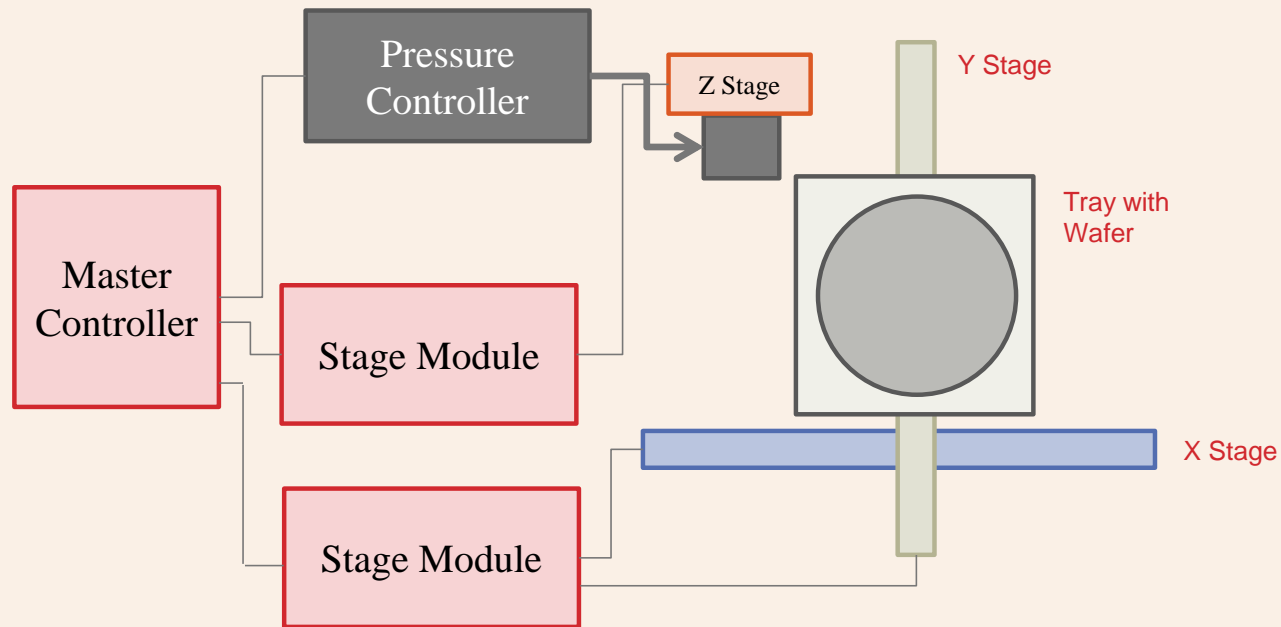
XY Stage

Greatly reduced force: for 1 mm diameter nozzle opening, 500 kPaG (73 psig, 5 bar(g)) results in force of 392 mN (8.8e-2 lbf).



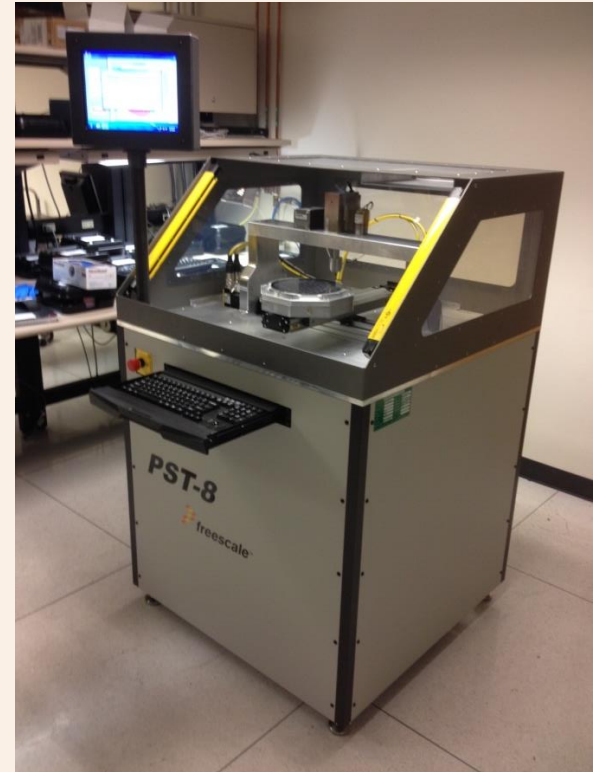
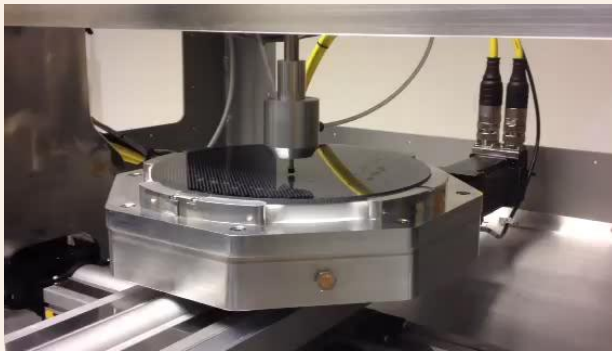
Final Concept

Test Small Portion of Wafer – Pressure Nozzle w/ XY Stage

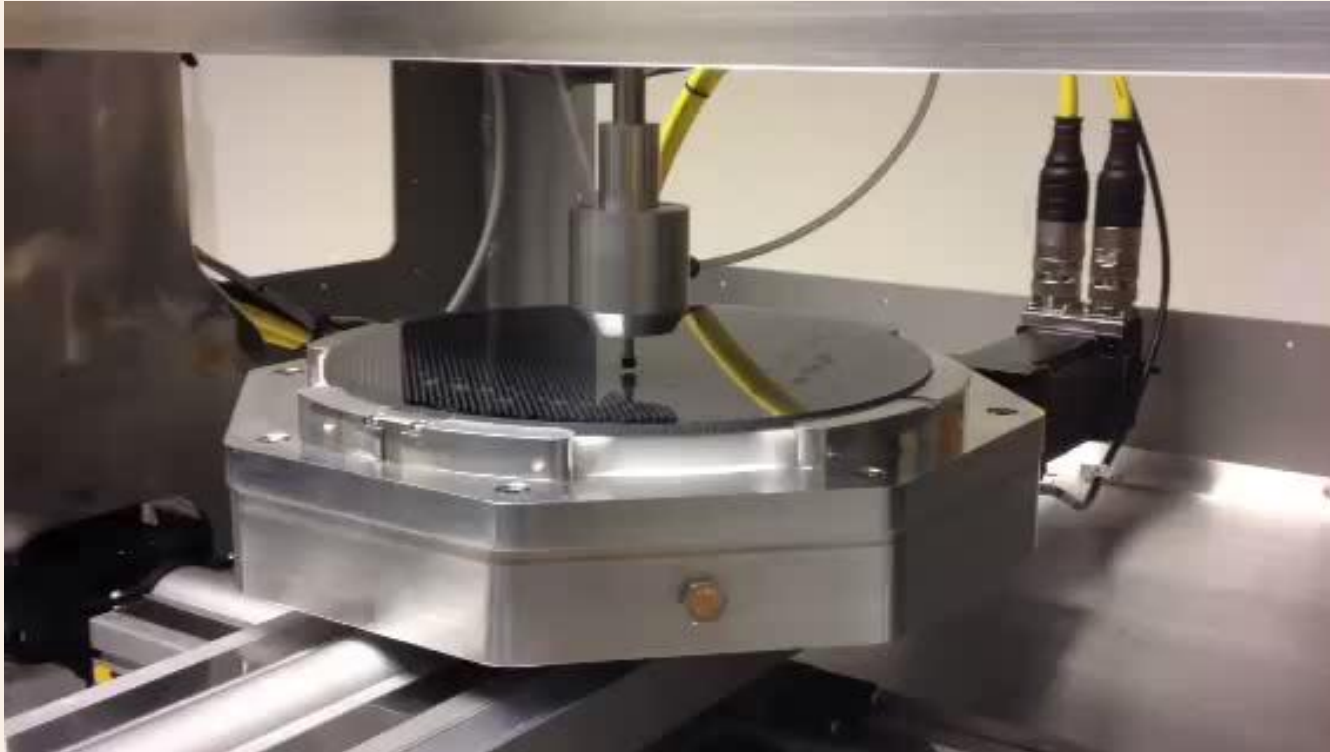


PST-8 (Phase I)

- Pressure Stress Test
- PST-8 System
 - 500 kPaG to “blow out” weak devices before probe
 - Test time 2 sec/DUT
 - 1.7 hour/wafer
- Capable of 2000 kPaG to characterize (destructively) the burst strength.

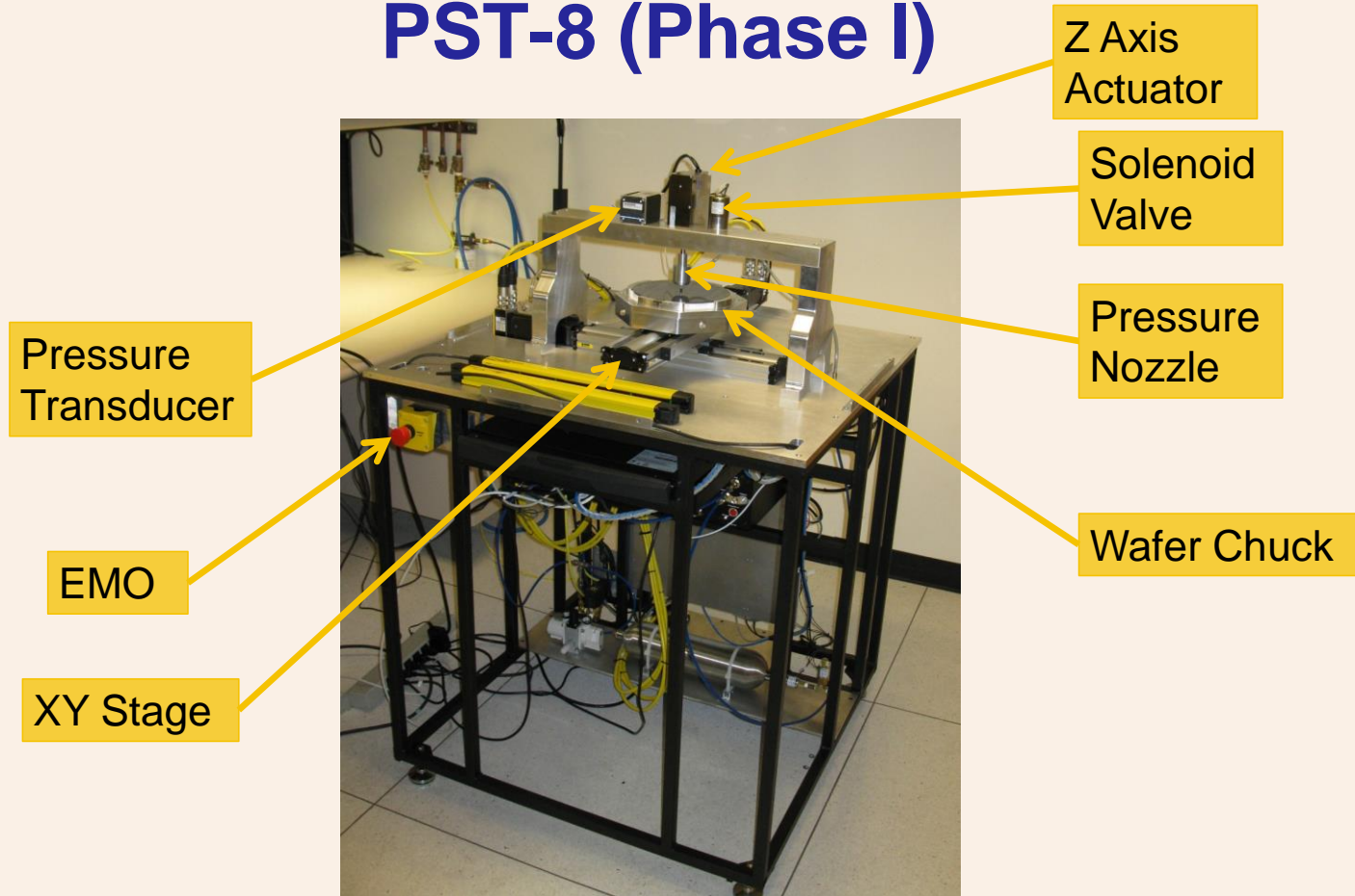


Production Test

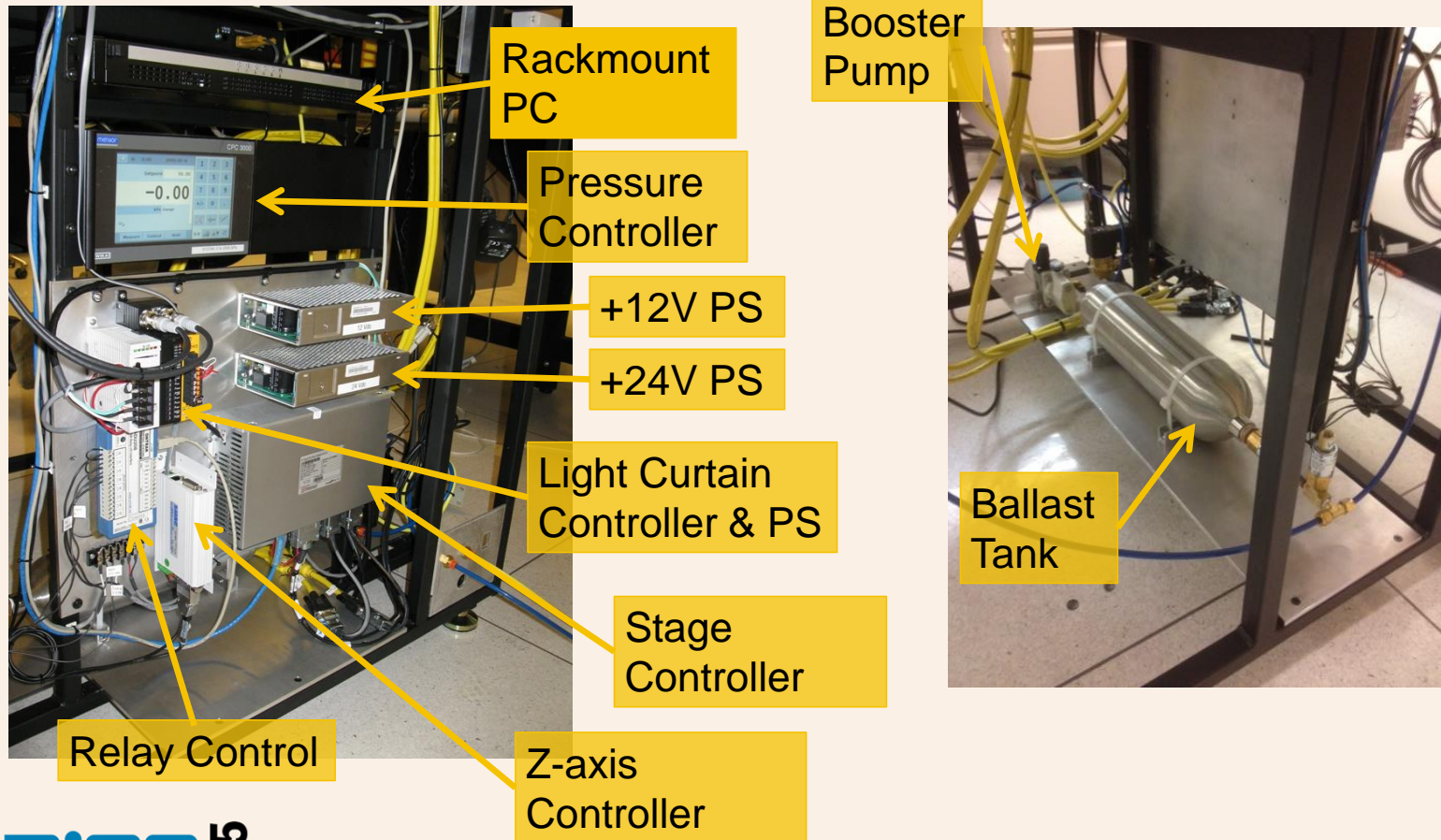


Pressure Stress Test in action (Video)

PST-8 (Phase I)

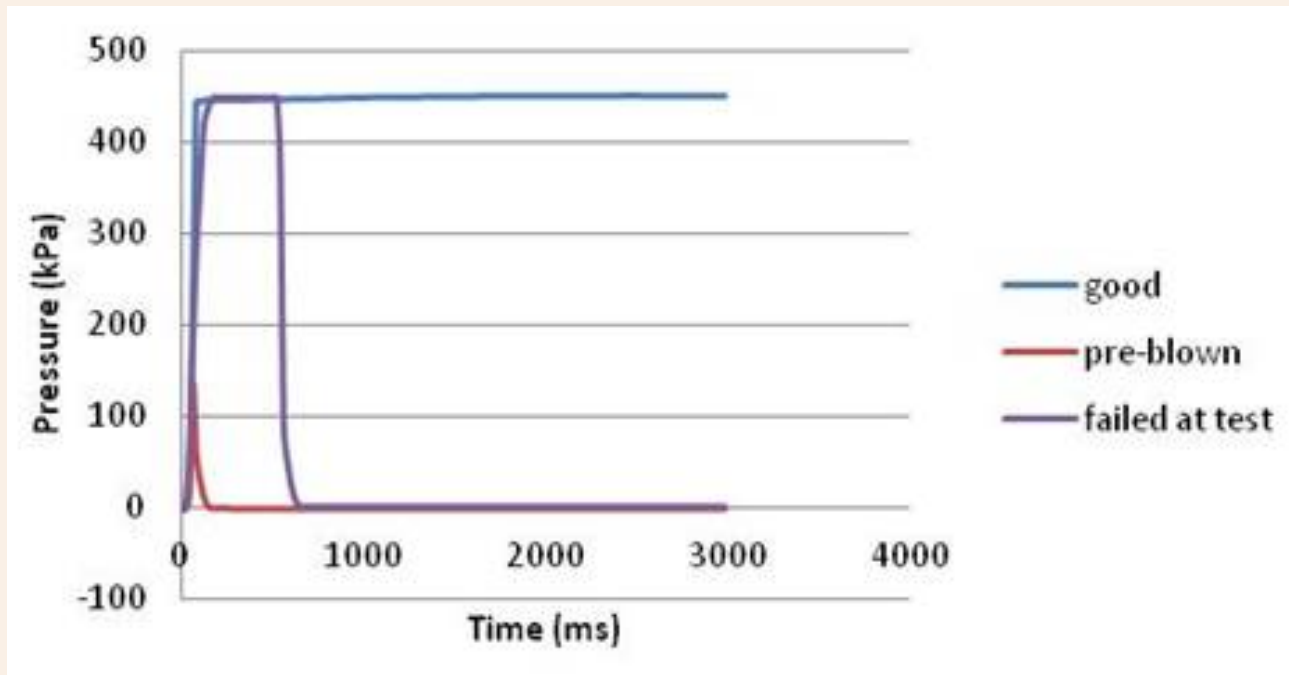


PST-8 (Phase I)



Pressure Profile

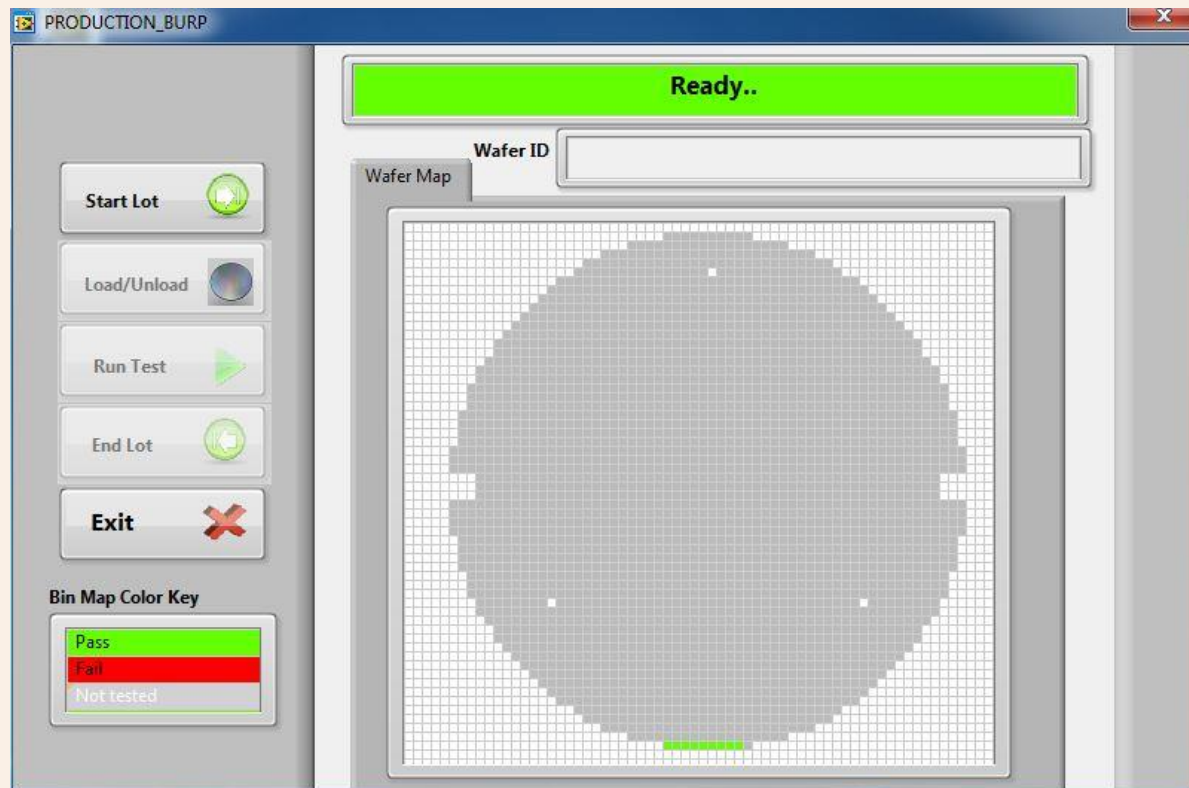
Detect failure by looking for pressure drop at nozzle



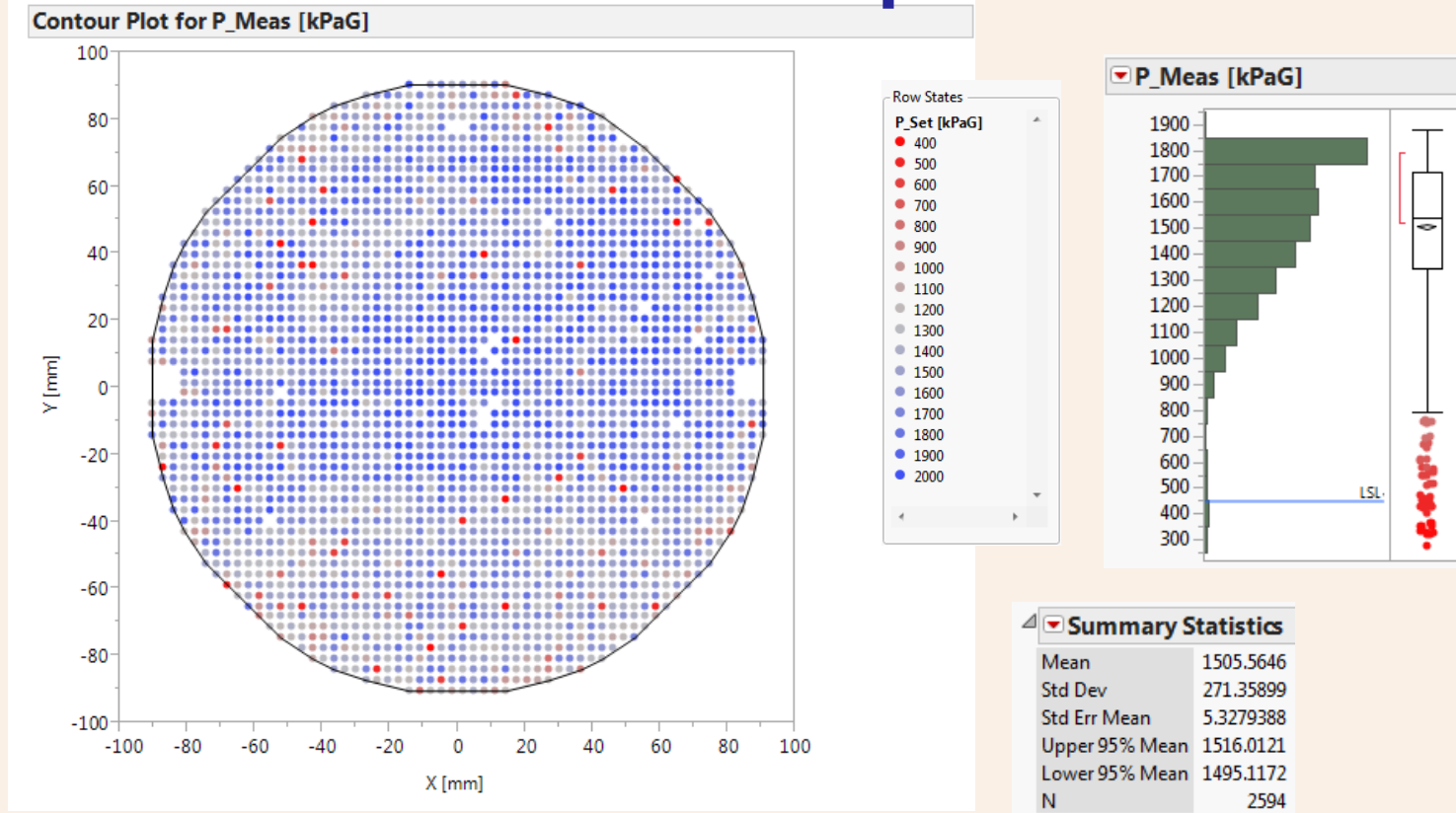
Note: This particular test used a pressure of 450 kPaG.

Operator Interface

- LabVIEW based
- Touch Screen Interface

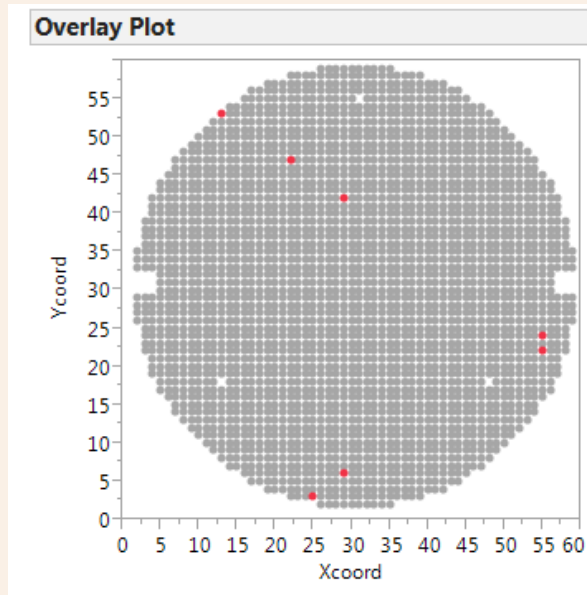


Pressure Ramp Mode

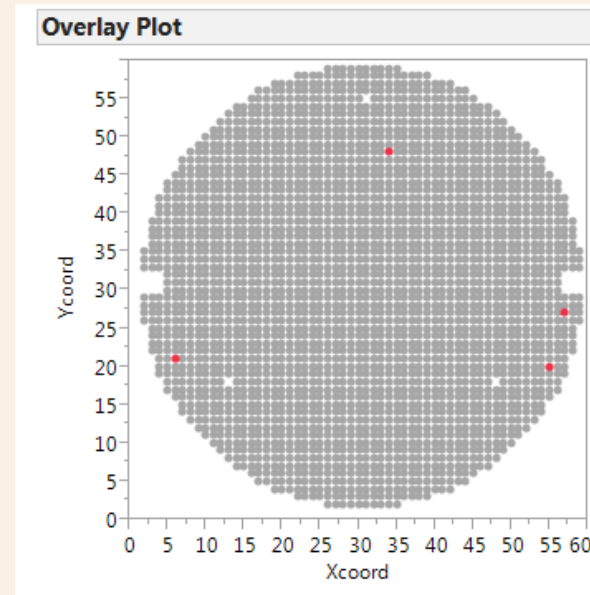


18 devices did not fail even at 2000 kPaG.

Pass/Fail (Production) Test



Wafer 7



Wafer 15

Wafer 7

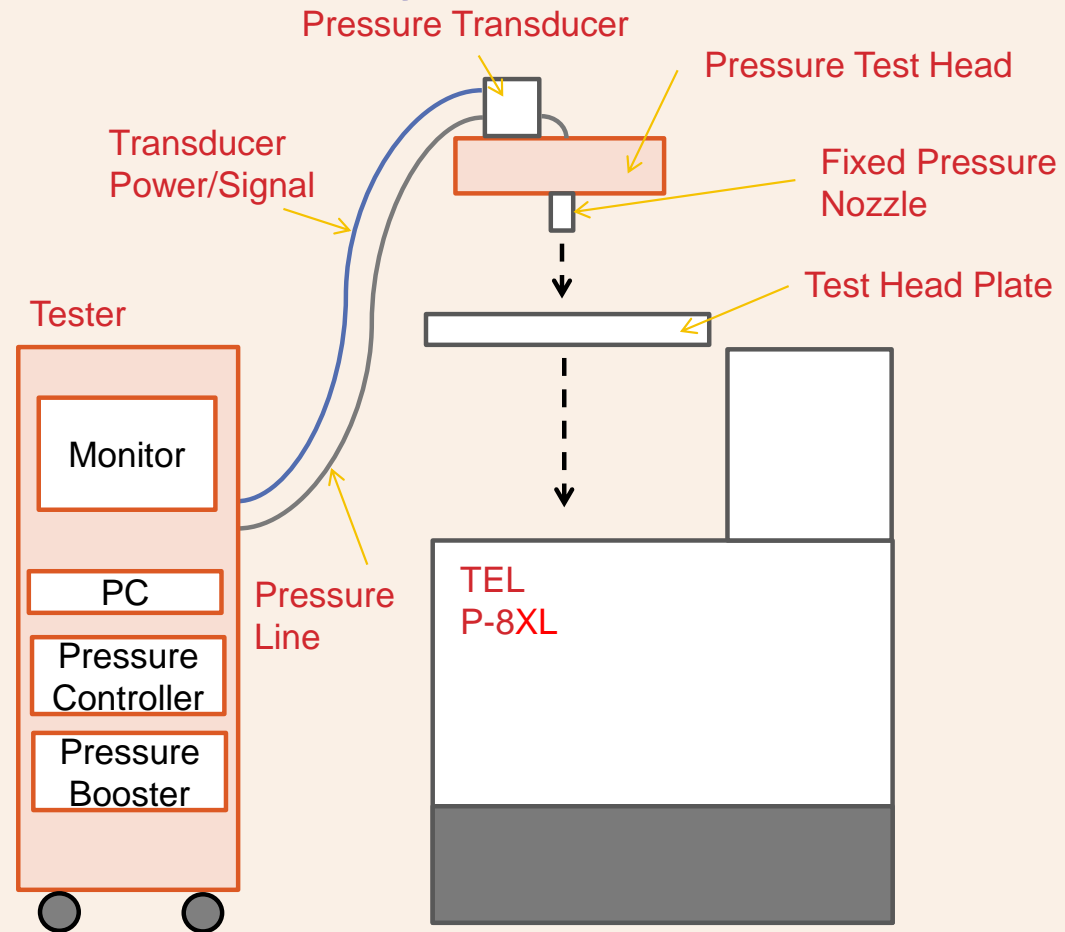
7 failures

Wafer 15

4 failures

Phase II System

- Solution for off-the-shelf prober
- x2 Parallelism
- A custom tray was developed to hold the wafer device side down, with clearance for air outflow. Sticky tray film will catch debris from the blown diaphragms.

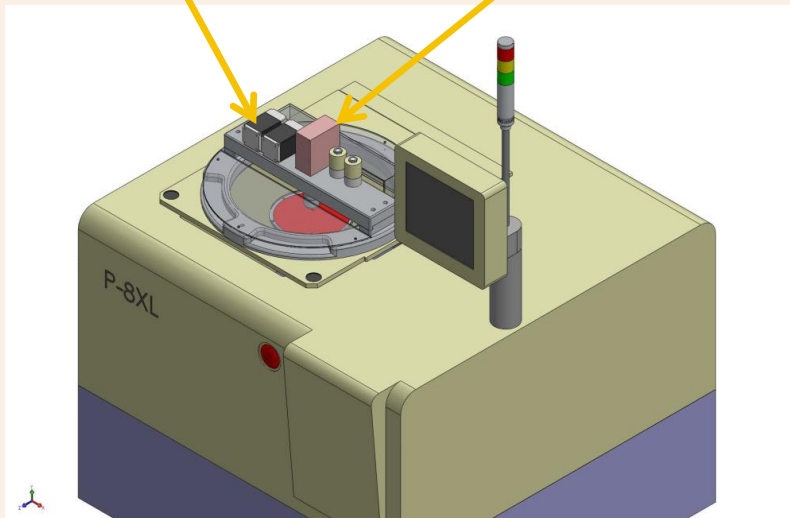


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Phase II System

2 Pressure
Transducers

Z-Axis
Actuator



Conclusion and Remarks

- Build a custom pressure system because nothing similar was commercially available.
- In the future, can the Test Equipment Industry provide economical solutions for testing pressure sensor devices.